

Pressure-enhanced robustness of helical edge state in ABA Tri-layer Graphene

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Multi-layer graphene systems are promising platforms to study interesting physical phenomena, including unique quantum hall physics, spontaneous symmetry breaking, and topological properties. Here, by applying hydrostatic pressure on the tri-layer ABA graphene, the phase diagram at the charge neutrality point undergoes a significant change, indicating a complicated interplay among different energy scales. Also, quantum parity hall state, a kind of helical edge state protected by mirror symmetry, emerges after pressure. The measured Landau Fan diagram illustrates the modification of the band structure by pressure, which can be used to explain the observed phenomenon.

INTRODUCTION

Regarding multilayer graphene systems, their rich physical properties make them widely regarded as a platform for studying unconventional properties of two-dimensional electron systems. Up to now, many intriguing physical phenomena has been found in multilayer graphene systems, ranging from single-particle to many-body physics, such as the Lifshitz transition of Fermi surface topology [1, 2], Landau level physics in the single-particle picture [3–6], quantum hall ferromagnetism even fractionalization under a high perpendicular magnetic field [7–17], and various symmetry broken states near charge neutrality and under a relatively small magnetic field [18–21]. Besides these phenomena, insulating bulk states with non-trivial edge channels can emerge in various graphene systems under different conditions, including chiral and helical edge states [19, 22–29].

Among them, tri-layer ABA graphene has attracted widespread attention due to its unique band structure at low energy regime. As a highly tunable platform, it provides an excellent opportunity to study its single-particle band structure and many-body phenomenon. In previous studies, its electronic properties have been studied by tuning multiple control knobs like carrier density, displacement field, and magnetic field, which lead to many interesting discoveries in this system [2–6, 15–17, 19, 20]. Notably, because the low-energy band structure of multilayer graphene is highly sensitive to the interlayer hopping strength, applying hydrostatic pressure to reduce the interlayer distance and further study its properties has become a highly promising research approach.

In recent years, condensed matter physics has witnessed a growing interest in exploring the topologically non-trivial edge states in materials. As an extension of the chiral edge state, the helical edge state is a special boundary state featured by the non-dissipative channels with opposite motion directions. Helical conductors have been proposed to realize Majorana statistics for quan-

tum computation [30–33]. Since its first theoretical proposed [34, 35], multiple ways are developed to achieve helical edge states, including topologically non-trivial band structures protected by time-reversal symmetry, such as those found in QSHE systems [36, 37]. In addition, in those systems where the conduction band is energetically below the valence band, the introduction of a magnetic field can cause the crossing of “hole-like” Landau levels with “electron-like” Landau levels at the system’s boundary, leading to the emergence of spin-degenerate helical edge states which are composed of opposite-propagating chiral edge states. The advent of multilayer graphenes has provided a fertile platform for exploring different types of helical edge states because of the unique band structure near the charge neutrality point (CNP). Many experimental evidence has confirmed the existence of helical edge states in multilayer graphene systems, ranging from monolayer to tetralayer graphene [19, 23, 24, 26, 38].

Here we report the dramatic change of phase diagram at the charge neutrality point and the emergence of a kind of helical edge state, named quantum parity hall effect, after applying 1.0 GPa hydrostatic pressure. Tri-layer ABA graphene is one of the material platforms which can hold helical edge states owing to its unique band structure. The low-energy band structure of tri-layer ABA graphene consists of a monolayer-like valence band and a bilayer-like conduction band in the absence of displacement field, which have an energy overlap, as shown in Figure 1(b). Both branches are protected by mirror symmetry and have odd(monolayer) or even(bilayer) parity. However, when a displacement field is applied, they mix due to the breaking of mirror symmetry.

METHOD AND CHARACTERIZATION

Here, we fabricate the tri-layer ABA device that has high mobility for observing its quantum hall effect, and we changed its band structure and phase diagram by exerting hydrostatic pressure out of the plane. Our device

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is a high-quality dual-gate device with a Hall-bar geometry, with hexagonal boron nitride(h-BN) as the dielectric spacer and few-layer graphite as the top and bottom gates, which is stacked together using a dry-transfer method [39]. In detail, the tri-layer ABA graphene is encapsulated by two hBN sheets whose geometric capacitances are C_t, C_b , respectively, in the unit of $V^{-1}cm^{-2}$. Moreover, outside of hBN sheets, two graphite stacks act as top and bottom gates. By modulating the top gate voltage V_t and bottom-gate voltage V_b , the carrier density $n(10^{12}cm^{-2})$ and out-of-plane displacement field $D(V/nm)$ can be tuned continuously, according to the relation:

$$\begin{aligned} n &= C_t V_t + C_b V_b \\ D &= \frac{1}{2\epsilon_0}(C_t V_t - C_b V_b) \end{aligned} \quad (1)$$

with ϵ_0 the vacuum permittivity. So, this configuration enables us to measure its transport properties with multiple in-situ tunable external parameters.

We also utilized hydrostatic pressure to reduce the interlayer distance and strengthen the interlayer coupling. It can change the material structure of Van der Waals(VdW) material systems without enhanced disorder effect, thanks to their weak out-of-plane VdW bonding. Previous work shows that hydrostatic pressure can compress the interlayer distance of graphene superlattice by 5% with less than 2.5 GPa[40] and can induce superconductivity in twisted bilayer graphene away from magic angle[41]. Therefore, hydrostatic pressure is a powerful tool for tuning the electronic structure effectively. Here, we mainly investigate the change of the device under a 1.0 GPa hydrostatic pressure by comparing it to that in ambient pressure.

The high quality of this device can be verified by the dependence of longitudinal resistance as a function of n and D . An external out-of-plane displacement field opens a gap at the charge neutrality point, schematically shown in Fig. 1(b). Fig. 1(c) and (d) show the resistance of the device at zero magnetic fields before and after pressurization. It is found that, along the charge neutrality point, the resistance of both increases dramatically, which indicates the appearance of an electric-field-induced band gap. This signature reflects a good quality and low disorder of our device before and after pressurization, which enables us to study the sample's band structure using the Landau fan diagram under an out-of-plane magnetic field.

In this work, transport measurements were conducted on this tri-layer ABA graphene device before and after 1.0 GPa pressure at a temperature $T = 1.6K$, and our findings are three-fold. Firstly, we explore the phase diagram of the tri-layer ABA graphene at the charge neutrality point as a function of the magnetic field and displacement field, by making a slow scan of the displacement field around and magnetic field around. The one after pressure reveals a complex competition between different energy scales. Interestingly, we

observe the signatures of some helical edge state after pressure, indicated by its nearly quantized four-terminal longitudinal conductance and near-zero transverse resistance. This state fades away when D is large enough, demonstrating that it is protected by mirror symmetry, which is broken under a finite D field. Secondly, in order to partially explain the observed phenomenon above, we perform the magneto-transport measurement to investigate how the pressure modifies the hopping parameters. Specifically, the Landau fan diagram shows that the crossing points among Landau levels undergo a significant shift, appearing at a larger magnetic field at 1.0 GPa pressure. This phenomenon indicates that the strength of interlayer hopping, alternatively, the low energy band structure, can be modified by pressure. Finally, our magneto-transport measurement finds some signatures of the four-fold quasi-degenerate zeroth monolayer-like Landau levels, which cannot be explained under the single-particle picture. These signatures include the complete splitting of these degenerate Landau levels at a relatively high magnetic field (about 10 T) before and after pressure. Besides, we found the Landau level splitting at the intermediate magnetic field only after pressurization. These two signatures indicate that the enlarged Landau level gaps, which are inconsistent with the single particle picture, should be associated with enhancing interlayer exchange interaction.

RESULTS

Phase diagram of $\nu = 0$ at small B

We first investigate the phase diagram of tri-layer ABA graphene around the charge neutrality point by measuring the four-terminal longitudinal conductance $G_{xx}(\frac{e^2}{h})$ under small magnetic field and displacement field. Figure 2(a) and 2(b) show this before and after pressure. As can be seen, the phase diagram at 1 GPa reveals a very different phase diagram than that at 0 GPa.

Firstly, the phase diagram at 0 GPa is similar to that observed in [19]. The conductance around $B = 0T$ and $D = 0 V/nm$ is the highest because of the metallic property caused by the overlap between the valence and conduction bands. As $|D|$ increases, opening a band gap at the charge neutrality point leads to a quick decrease of G_{xx} , indicating the high quality of our sample. In addition, along the $D = 0 V/nm$ line profile, a local minimum of G_{xx} emerges around $B = 0.25T$, indicated by the green arrows, surrounded by a high-conductance ring. This signature demonstrates that the nature of this state is different from that at higher B or zero B . According to [19], a similar state is interpreted as the ‘‘Quantum Parity Hall State’’ (QPH) which has nearly quantized four-terminal longitudinal conductance. However, here, we do not observe this well-defined features to claim its edge state configuration so that it should be regarded as

an incipient of QPH, demonstrating it is not very stable at a temperature as high as $T = 1.6\text{K}$. In contrast, the temperature in [19] is 0.4K .

However, at 1 GPa , the phase diagram becomes very different: the high-conductance state near $B = 0\text{T}$ and $D = 0\text{V/nm}$ has shrunk into a much smaller region, and more features appear as B and D changes. The first interesting feature is the appearance of spikes of longitudinal conductance $G_{xx}(B, D)$ within a small range of $B \in [0.3\text{T}, 0.8\text{T}]$, marked by the dashed-line trajectories of different colors in Figure 2(b). These features refer to the phase boundaries of first order phase transitions, which is accompanied by a sudden change of charge distribution among several flavours [42], driven by the competition between displacement field and magnetic field. Similar transport signatures have been found in bilayer graphene and rhombohedral tri-layer graphene, but requires larger magnetic field [18, 25, 26, 28]. We find that one of the phase boundaries display a parabolic-like trajectory at low B (marked by a purple dashed line) and linear trajectory at high B (marked by a green dashed line), whereas another one also displays a linear behaviour (marked by a orange dashed line). These boundaries demonstrate the competition between different energy scales. Based on these phase boundaries and other features, we can divide the phase diagram at charge neutrality point into several regions, and four of them are labelled as A, B, C, D as shown in Figure 2(c).

The phase boundary between phase A and phase B could be possibly explained by the competition between exchange interaction caused by B and layer polarization driven by D , since the exchange interaction proportional to $\frac{e^2}{l_B} \sim \sqrt{B}$ whereas the layer polarization characterized by $\Delta_1 = \alpha dD$, with $\alpha \approx 0.3$ the empirical parameters describing the screening effect and $d \approx 0.3\text{nm}$ the nearest interlayer distance. Following the analysis of [7, 19], one role of magnetic field is to tune the strength of exchange interaction, whereas the displacement field favors a layer polarization. So it is reasonable that the competition between phase A and phase B is driven by these energy scales. In contrast, either the phase boundary between phase C and phase B or phase D and phase B, displays a linear-shape trajectory, indicating a different mechanism from that one between phase A and phase B. These linear dependence indicates the energy scale associated with B should also be linear with B . From some theoretical work [7], the Zeeman energy E_{ZM} , difference between intralayer and interlayer exchange interaction δE_{ex} and electrostatic energy E_H are all linear functions of B . Therefore, it is possible that these two phase boundaries appear because of the complex competition between Δ_1 and $E_{ZM}, \delta E_{ex}, E_H$.

To better manifest the distribution of electrons in spin and layer flavours, the possible state configurations of phase A/B/C/D are given in the Figure 2(c). It is well acknowledged that when D is large enough, the phase would be layer-polarized in order to minimize the ground state energy, mainly driven by the energy

scale $\Delta_1 = \alpha edD$. Therefore the phase C should be fully layer polarized and spin unpolarized. On the other hand, the phase A and phase D should be both spin and layer unpolarized. As discussed below, the phase A holds a non-trivial helical edge state which is spin degenerate. Also, in the absence of displacement field D , the state should have the mirror symmetry which requires zero layer polarization. An interesting problem is what's the configuration of phase B? The appearance of conductance spikes indicate a sudden change of distribution in spin and layer flavours either between phase A/D and phase B or between phase C and phase B. So it is possible that phase B should have some kind of spin polarization. In addition, the slope of boundary between phase B and phase D is almost twice of that between phase B and phase C. This approximate 2:1 ratio may be related to the energy scale associated with the layer coupling. It's possible that the transition between phase A to phase B requires electrons transfer between the two interlayer interfaces (middle layer to top layer and bottom layer to middle layer) whereas the transition between phase C to phase B only requires electrons transfer between one interlayer interface (middle layer to top layer). Based on these, it is possible that the phase B has layer anti-ferromagnetism and is partially layer-polarized, as shown in the Figure 2(c).

Helical edge state protected by mirror symmetry

Next, we find the emergence of the helical edge states after pressurization, which is in the phase A in Figure 2(c). To see it clearer, we show the profiles of both four-terminal longitudinal conductance and transverse resistance along the linecut at $D = 0\text{V/nm}$ before and after pressurization in Figure 3(a) and 3(b). It can be seen that at 1GPa , there is a prominent nearly quantized plateau in the longitudinal conductance profile which reaches to about $4\frac{e^2}{h}$ (actual $4.1\frac{e^2}{h}$) in a magnetic field ranging from 0.3T to 0.8T , while the transverse resistance drops almost to zero under the same condition. This signature indicates there are two pairs of helical edge states in the phase A.

However, this topological edge state can be destroyed either by increasing B or increasing D . In addition, we extract out the line profiles of G_{xx} at different B in the range of $[0.40\text{T}, 0.60\text{T}]$, shown in the Figure 3(c). It can be seen that the when the displacement field is large enough, the nearly quantized G_{xx} goes through a drastic increase, indicating the state at $D = 0\text{ V/nm}$ is protected by the mirror symmetry, therefore it is the quantum parity hall state that mentioned in [19]. This state is a kind of helical edge state, an analogy to QSHE. The origin of this state can be attributed to the crossing of the zeroth Landau level from the monolayer valence band $(m, 0)$ and the zeroth Landau level from the bilayer conduction band $(b, 0)$ at the sample boundary, forming four

spin-degenerate counter-propagating helical edge modes, while the bulk remains insulating, resulting in the quantization of the four-terminal longitudinal conductance G_{xx} to $\frac{4e^2}{h}$, which can be verified by Landauer-Buttiker formalism. Since the monolayer-like Landau level and bilayer-like Landau level are only valid with the preservation of mirror symmetry, a relatively large displacement field can break this symmetry and hybridize these two types of Landau levels, which leads to the disappearance of the Quantum Parity Hall state.

In addition, the state in [19] exists at temperature 0.4K, whereas the state in our sample emerges at a higher temperature about 1.6K, showing a more robust behaviour against temperature effect. On the other hand, the unstability of this state before pressure, indicating that some interlayer hopping parameters may play an important role on the robustness of this state. Indeed, according to [19], the ground state energy of QPH can be expressed as

$$E_{QPH} = -\frac{15}{4} \sqrt{\frac{\pi}{2}} \frac{e^2}{\epsilon l_B} - 3\Delta_{mb} - \dots \quad (2)$$

(...omits other terms) where Δ_{mb} is the energy scale which characterizes the overlap between the valence band of monolayer-branch and the conduction band of bilayer-branch as shown in Figure 3(d). This expression tells that larger the Δ_{mb} , more stable the QPH state is. To have a more detailed analysis, we have to figure out how the this parameter changes after pressurization in our device. By doing this, we have to figure out how the interlayer hopping parameters are modified after pressurization.

Extract hopping parameters by Landau Fan diagram

In order to extract the value of hopping parameters, we perform the magneto-transport measurement at these two pressures in the absence of displacement field D, following the similar procedures in [3, 4]. the Figure 4(a) and 4(d) show the four-terminal longitudinal resistance R_{xx} as a function of carrier density n and magnetic field B , named Landau Fan diagrams, which reflect the evolution of Landau levels in tri-layer ABA graphene as the magnetic field changes. At relatively large magnetic field (here 3T), a series of oscillations of broad minima which are separated by broad maxima, start to appear as a pattern that each minimum represents the completely filling of one Landau level or several quasi-degenerate Landau levels. The slope of each minimum track corresponds to a filling factor $\nu = n \frac{h}{eB}$, where e is the electron charge, h is the Planck's constant, and n is the Landau level index. Most of the visible minimum tracks were traced out, shown in the Figure 4(b) and 4(e).

In Figure 4(a) and 4(d), there are several crossing points with the enhancement of R_{xx} which are caused

by the crossing of zeroth Landau levels from the monolayer branch ($m, 0$) and some lowest Landau levels from the bilayer branch (b, i), and the positions of these crossing points can be used to determine the hopping parameters. The most visible crossing points are marked as cyan dot (P1), red dot (P2), black dot (P3) in both Figures, which can be identified by (ν, B) , and they depend on the hopping parameters of tri-layer ABA graphene sensitively. It can be seen that the positions of P1, P2, P3 in Figure 4(b) shift upward to higher fields than that in Figure 4(a), which clearly indicates the modification of hopping parameters after pressure.

The six-band continuum model which includes all the SWMC parameters ($\gamma_0, \gamma_1, \gamma_2, \gamma_3, \gamma_4, \gamma_5, \delta, \Delta_2$) is used to qualitatively reflect the modification of interlayer hopping strength, which can be determined by using the positions of crossing points as inputs. The SWMC parameters can be classified as two types: the intra-layer type (γ_0) which are not influenced by inter-layer distance d and the inter-layer type ($\gamma_1, \gamma_2, \gamma_3, \gamma_4, \gamma_5, \delta, \Delta_2$) which sensitively depends on d . Here, the positions of P1, P2, P3 were determined as (6, 4.60), (10, 2.40), (14, 1.80) in the Figure 4(a) and (6, 5.50), (10, 3.00), (14, 2.23) in the Figure 4(b). Then we optimize these parameters to fit these positions with the consideration of disorder effect $\Gamma = 0.8$ meV. The fitting results are shown in Table I, and they were used to get the simulated Landau level spectra as shown in Figure 4(c) and 4(f), the positions of Landau levels crossing points (marked by dots of the same colours as in the Figure 4(a) and 4(d)) match well with the experimental result. The important parameter in formula (2), Δ_{mb} was found several meV larger after pressure: it is 14.3 meV at 0 GPa whereas 18.4 meV at 1GPa which has increased about 4 meV after pressure. This expected result can explain the enhanced stability of quantum parity hall state since its ground-state energy greatly lowered.

Features beyond single-particle picture

Within single-particle picture as shown in Figure 4(c) and 4(f), the zeroth Landau levels of monolayer-like branch and some lowest Landau levels of bilayer-like branch are almost degenerate within the valley-spin subspace. With disorder effect ($\Gamma = 0.8$ meV), a set of four-fold Landau levels should be regarded as a four-fold degenerate Landau level, which show in the Landau fan as a single minimum track instead of four splitting minimum tracks. However, the four-fold degeneracy of zeroth Landau level of monolayer-like branch can be lifted off completely at relatively high field both in Figure 4(a) and 4(d), and at even lower field in Figure 4(d).

This splitting directly indicates the Landau level gaps becomes larger to make each one isolated with others even with the disorder effect. There are several possible sceneries for this phenomenon: enlarged single-particle

gap at large magnetic field, the suppression of disorder effect, and enhanced electron-electron interaction. However, the first two sceneries can be eliminated here with the analysis below. First, the energy of the zeroth Landau levels of monolayer-like branch is $-\frac{\gamma_2}{2} + \Delta_2$ at K valley and $\delta - \frac{\gamma_5}{2} + \Delta_2$ at K' valley, which are not dependent on the magnetic field. This fact eliminates the first one since the Landau level gaps is unchanged. As for the second one, it is also unlikely since the bilayer-like Landau levels doesn't show a clear completely splitting signature at the same magnetic field, even though the gap is larger as shown in the simulation results. In addition, our simulation results show that the zeroth Landau levels of monolayer-like branch are almost degenerate, so even doesn't take the disorder effect into account, the degeneracy shouldn't be totally broken in the single-particle picture. Therefore, this scenario is not possible either. So only the last one, the effect of interaction, can be responsible for it. This phenomenon should be associated with the spontaneous symmetry-breaking caused by exchange interactions among Landau levels, named quantum hall ferromagnetism which beyond the single-particle picture[7–10, 14–17].

The characteristic energy scale of exchange interaction between Landau levels can be estimated as $E_{ex} = \frac{e^2}{\epsilon l_B} \sim \sqrt{B}$, where $\epsilon \approx 6.6$ is the in-plan h-BN dielectric function. At $B = 10\text{T}$, the strength of this interaction can be as large as 27 meV, which is much larger than the single-particle Landau level gaps within the spin-valley subspace. So the electron-electron interaction should not be simply neglected at relatively high field, it can mix all the possible single-particle states together to form new states that spontaneously breaks the SU(4) symmetry. What's more, the interaction scenario can also be used to explain the splitting happened at a lower field after pressure. The reduction of interlayer distance d can enhance the inter-layer exchange interaction, which may be important in tri-layer ABA graphene since the monolayer-like branch is layer-coherence. Since the exchange interaction favors symmetry-breaking states, it is possible that the enhancement of inter-layer exchange interaction can help enlarge the gaps even in a relatively lower field. However, there are some doubts that why this enhance-

ment of inter-layer exchange interaction can't enlarge the gaps in bilayer-like branch. Maybe it also relates to the orbital nature of the zeroth Landau level in monolayer-like branch which is only associated with $n=0,1$ Landau levels. A further study of this phenomenon can be done to reveal the physics behind it, which may be helpful to study the quantum hall ferromagnetism in tri-layer ABA graphene.

CONCLUSION

In conclusion, this work reveals the highly tunable properties in tri-layer ABA graphene by hydrostatic pressure. It is seen that not only the hopping parameters can be tuned by pressure directly, but the phase diagram in the low magnetic field can also have a significant change. These phenomena demonstrate that tri-layer ABA graphene can be a high-tunable platform for band engineering and a variety of phases with pressurization. It is the emergence of the "Quantum Parity Hall state," which is a helical edge state with two pairs of counter-propagating edge modes. Moreover, several novel states are favoured by different energy scales at the charge neutrality point. However, there are still some questions which still need to be answered. The first one is about what the nature of the phase B. In order to answer it, it is necessary to use the temperature-varied and tilted magnetic field transport measurement to get a more detailed understanding of the competition between different energy scales. Since the perpendicular magnetic field controls the exchange effects and the LL degeneracies, they may play an important role in determining the phase diagram, revealing the complex Landau-level structure of tri-layer ABA graphene. We hope our experimental results can trigger some theoretical and experimental interests to investigate it deeper.

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Coming Soon !

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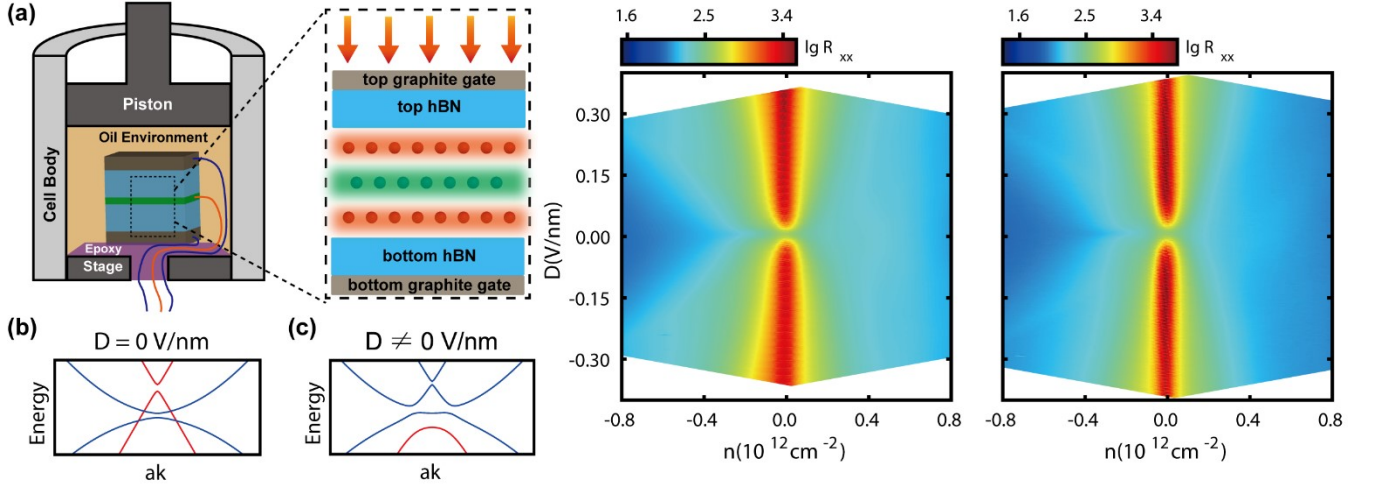


FIG. 1. Schematic of experimental setup and transport characterization.

(a) Schematics of hydrostatic pressure setup. (b), (c) Schematics of How the displacement field influences the band structure of tri-layer ABA graphene. In the absence of displacement field D , the low energy bands include two monolayer-like bands with linear dispersion (red curve & blue curve) and two bilayer-like bands with parabolic dispersion (cyan curve & green curve). When D is non-zero, these two bands hybridize, leading to a gap opening at the charge neutrality point, making the system insulate. (d), (e) device characterization before and after 1.0 GPa hydrostatic pressure by using the four-terminal longitudinal resistance R_{xx} as a function of carrier density $n(10^{12} \text{cm}^{-2})$ and displacement field $D(\text{V/nm})$. Along the charge neutrality profile, the resistance increases dramatically as D increases, indicating a gap opening reflecting the device's good quality.

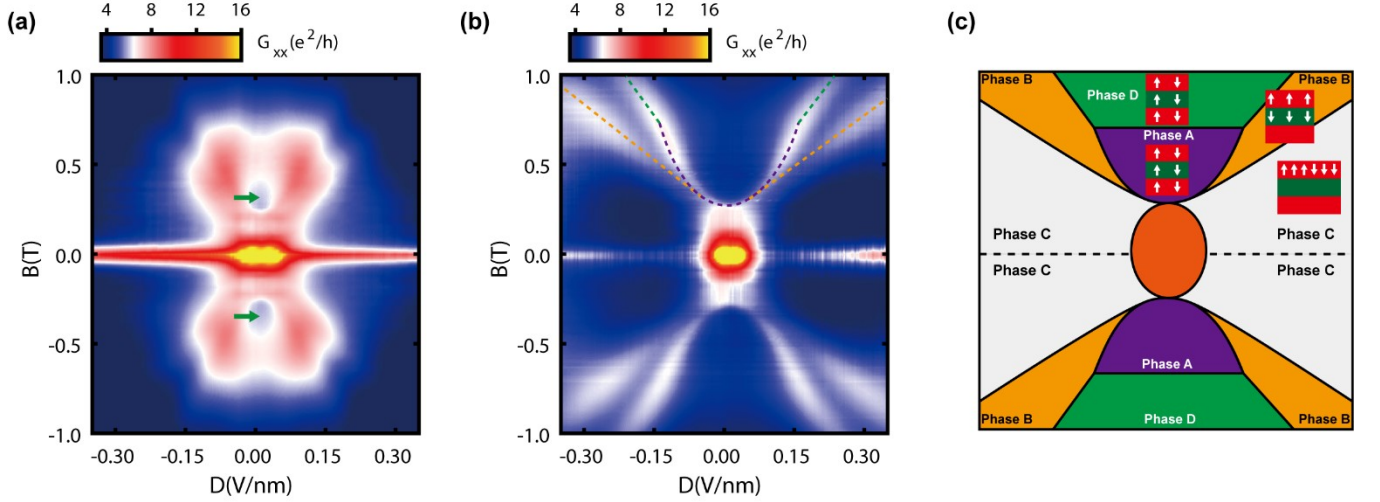


FIG. 2. Phase diagrams at the charge neutrality point before and after 1.0 GPa hydrostatic pressure.

Here, Figures 2(a) and 2(b) show the phase diagrams of four-terminal longitudinal conductance G_{xx} in unit of $\frac{e^2}{h}$ as a function of $B(\text{T})$ and $D(\text{V/nm})$, with B ranges from -1.0 T to 1.0 T and D ranges from -0.30 V/nm to 0.30 V/nm, it is noted that the values larger than 16 has been rescaled to 16. (a) shows the phase diagram at 0 GPa. A prominent feature emerges around $D = 0 \text{ V/nm}$ and $B = 0.3\text{T}$, indicated by the green arrow. (b) the phase diagram at 1GPa shows visible traces of phase boundary (marked by dashed lines of different colours), indicating first-order phase transitions between different ground states. This phase diagram is converted into a cartoon shown in (c). Different regions are filled with different colours, and specific phases are labelled with A, B, and C, demonstrating the existence of different ground states.

TABLE I. This is a table that records the fitting parameters at 0 Gpa and 1 Gpa based on the experimental results shown in figure.4(a)(b), the energy unit is set to eV. The intralayer hopping γ_0 is fixed as 3.100eV.

Pressure	γ_0	γ_1	γ_2	γ_3	γ_4	γ_5	δ	Δ_2
0 GPa	3.100	0.3845	-0.0194	0.3510	0.0653	0.0636	0.0415	0.0021
1 GPa	3.100	0.3784	-0.0234	0.3665	0.0612	0.0833	0.0534	0.0031

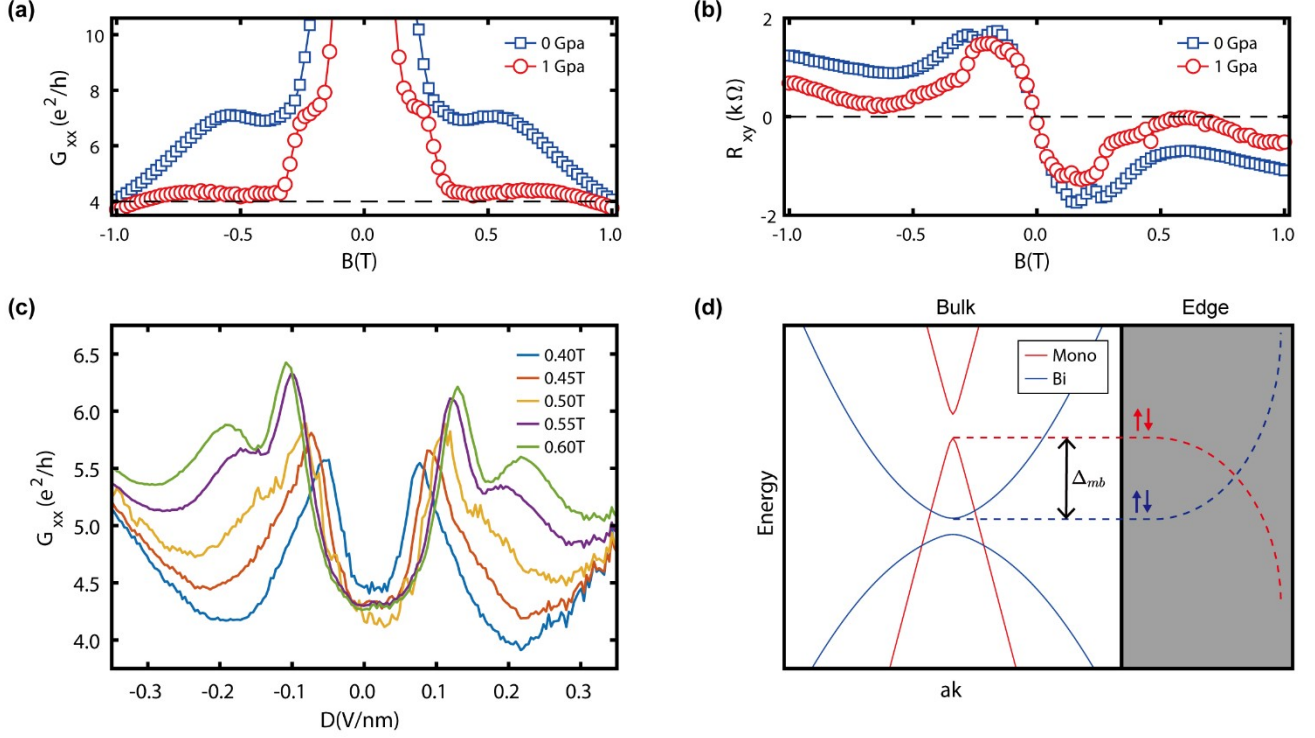


FIG. 3. Experimental signatures of Quantum Parity Hall effect and its schematics.

(a) The longitudinal conductance G_{xx} profiles of the $D = 0$ V/nm in both Figure 2(a) and 2(b), blue squares mark the 0 GPa curve, and red circles mark the 1 GPa curve. It can be seen that G_{xx} becomes nearly quantized (about $4.1 \frac{e^2}{h}$) after pressure. (b) The profiles of transverse resistance R_{xx} at $D = 0$ V/nm, where the 1 GPa curve almost reaches zero around $B = 0.6$ T, together with the nearly quantized signature in (a), indicating the appearance of helical edge states in the system, which is the quantum parity hall state (QPHE). (c) The profiles at $B = 0.40 / 0.45 / 0.50 / 0.55 / 0.60$ T are taken from Figure 2(b) as a function of displacement field D . The nearly quantized plateau disappears when D is large enough. (d) The schematic of the mechanism of (QPHE) based on the band structure: the edge states from the monolayer valence band and that from the bilayer conduction band propagate along opposite directions along the edge, and because of the spin degeneracy, there are four channels of edge states.

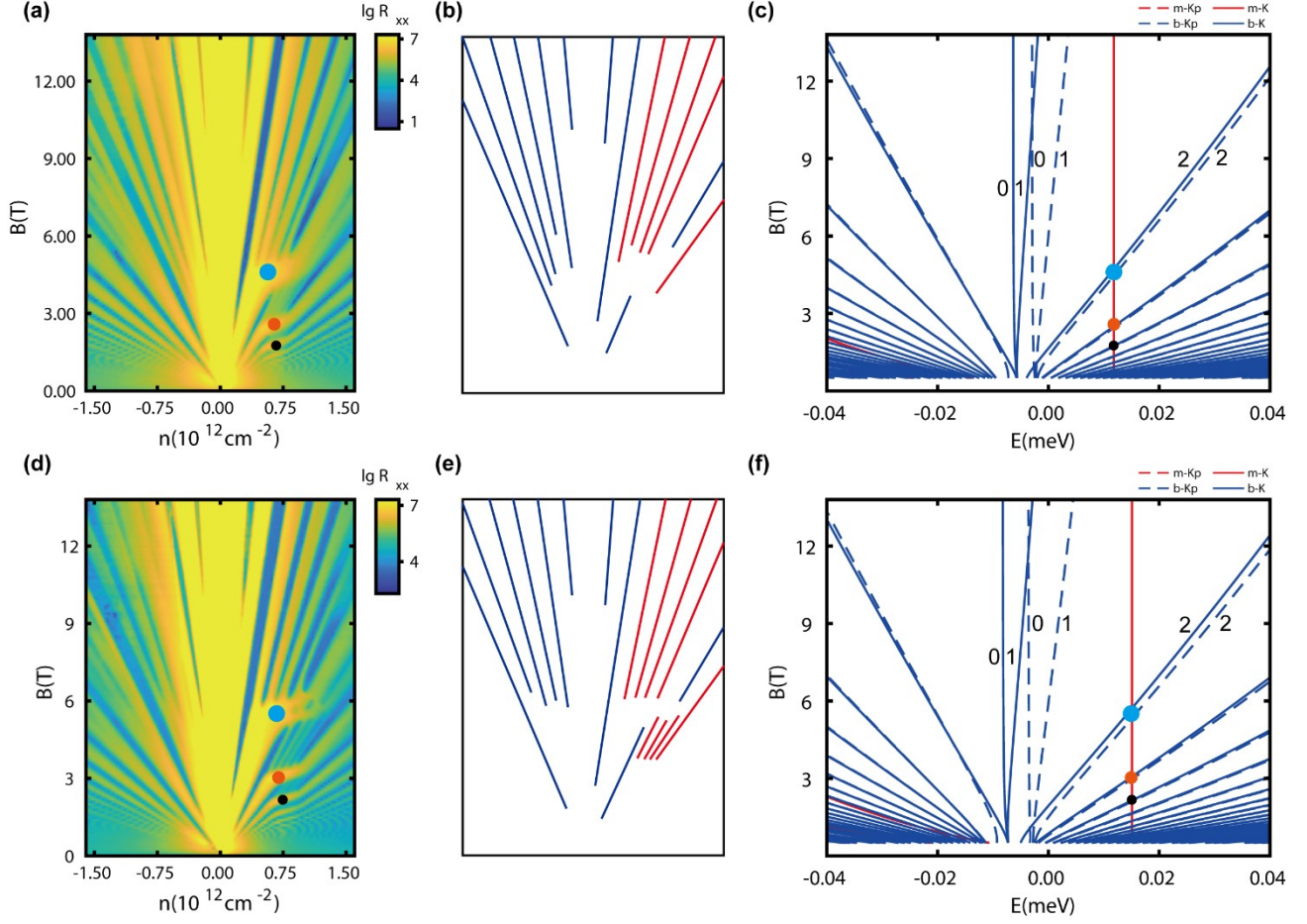


FIG. 4. Landau Fan diagrams at 0 GPa and 1 GPa, and the fitted simulation results.

(a), (d) the Landau Fan diagrams at 0 GPa and 1 GPa, the crossing points between $(m, K/K', 0)$ and $(b, K', 2)$, $(b, K', 3)$, $(b, K', 4)$ are marked by cyan, orange and black-coloured dots (P1, P2 and P3). It can be seen that the crossing points shift toward a large magnetic field after pressure. In (b) (e), some minimum tracks at low integer fillings (from -6 to 10) are traced out, the blue colour indicates that the LLs are from a bilayer-like branch while the red is from monolayer-like branch. (c), (f) the simulated Landau level structures fitted by the positions of crossing points from (a) and (b). The corresponding points are also marked in the figures. The monolayer-like Landau levels are red-colour, while the bilayer-like Landau levels are blue-colour (dashed line for K' valley and solid line for K valley). The numbers are the Landau level indexes in each branch. The fitting parameters are listed in Table I.